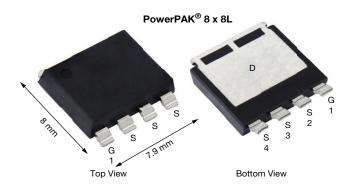
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Vishay Siliconix

# Automotive N-Channel 40 V (D-S) 175 °C MOSFET



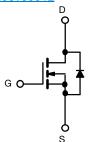
PRODUCT SUMMARY					
V <sub>DS</sub> (V)	40				
$R_{DS(on)}(\Omega)$ at $V_{GS} = 10 \text{ V}$	0.0019				
I <sub>D</sub> (A)	233				
Configuration	Single				
Package	PowerPAK 8 x 8L				

#### **FEATURES**

- TrenchFET® Gen IV power MOSFET
- AEC-Q101 qualified
- 100 % R<sub>q</sub> and UIS tested
- Thin 1.6 mm package
- · Very low thermal resistance
- Material categorization: for definitions of compliance please see www.vishav.com/doc?99912



ROHS COMPLIANT HALOGEN FREE



N-Channel MOSFET

ABSOLUTE MAXIMUM RATINGS (	$T_C = 25  ^{\circ}C$ , unles	s otherwise noted	l)		
PARAMETER	SYMBOL	LIMIT	UNIT		
Drain-source voltage		V <sub>DS</sub>	40	V	
Gate-source voltage		$V_{GS}$	± 20	V	
Continuous drain current	T <sub>C</sub> = 25 °C	1	233		
	T <sub>C</sub> = 125 °C	l <sub>D</sub>	134		
Continuous source current (diode conduction)	I <sub>S</sub>	170	Α		
Pulsed drain current <sup>a</sup>		I <sub>DM</sub>	930		
Single pulse avalanche current	L = 0.1 mH	I <sub>AS</sub>	38		
Single pulse avalanche energy	L = 0.1 MH	E <sub>AS</sub>	72	mJ	
Maximum power dissipation	T <sub>C</sub> = 25 °C	P <sub>D</sub>	187	W	
	T <sub>C</sub> = 125 °C	$r_{D}$	62	VV	
Operating junction and storage temperature ran	T <sub>J</sub> , T <sub>stg</sub>	-55 to +175	°C		
Soldering recommendations (peak temperature)		260	C		

THERMAL RESISTANCE RATINGS							
PARAMETER	SYMBOL	LIMIT	UNIT				
Junction-to-ambient	PCB mount b	$R_{thJA}$	44	°C/W			
Junction-to-case (drain)		$R_{thJC}$	0.8	C/VV			

#### Notes

- a. Pulse test; pulse width  $\leq$  300 µs, duty cycle  $\leq$  2 %
- b. When mounted on 1" square PCB (FR4 material)
- c. See solder profile (<a href="www.vishay.com/doc?73257">www.vishay.com/doc?73257</a>). The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection



# Vishay Siliconix

PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNIT	
Static								
Drain-source breakdown voltage	V <sub>DS</sub>	$V_{GS} = 0$ , $I_D = 250 \mu A$		40	-	-	V	
Gate-source threshold voltage	V <sub>GS(th)</sub>	$V_{DS} = V_{GS}, I_D = 250 \mu A$		2	2.8	3.5	]	
Gate-source leakage	I <sub>GSS</sub>	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$		-	-	± 100	nA	
		$V_{GS} = 0 V$	V <sub>DS</sub> = 40 V	-	-	1		
Zero gate voltage drain current	I <sub>DSS</sub>	$V_{GS} = 0 V$	$V_{DS} = 40 \text{ V}, T_{J} = 125 ^{\circ}\text{C}$	-	-	50	μΑ	
		$V_{GS} = 0 V$	V <sub>DS</sub> = 40 V, T <sub>J</sub> = 175 °C	-	-	150		
On-state drain current <sup>a</sup>	I <sub>D(on)</sub>	V <sub>GS</sub> = 10 V	$V_{DS} \ge 5 V$	100	-	-	Α	
Drain-source on-state resistance <sup>a</sup>		V <sub>GS</sub> = 10 V	I <sub>D</sub> = 20 A	-	0.0015	0.0019		
	R <sub>DS(on)</sub>	V <sub>GS</sub> = 10 V	I <sub>D</sub> = 20 A, T <sub>J</sub> = 125 °C	=.	-	0.003	Ω	
		V <sub>GS</sub> = 10 V	I <sub>D</sub> = 20 A, T <sub>J</sub> = 175 °C	=.	-	0.0035		
Forward transconductance b	9 <sub>fs</sub>	V <sub>DS</sub> = 15 V, I <sub>D</sub> = 30 A		-	120	-	S	
Dynamic <sup>b</sup>								
Input capacitance	C <sub>iss</sub>		V <sub>DS</sub> = 25 V, f = 1 MHz	=.	3316	4643	pF	
Output capacitance	C <sub>oss</sub>	$V_{GS} = 0 V$		=	1137	1592		
Reverse transfer capacitance	C <sub>rss</sub>			-	134	188		
Total gate charge <sup>c</sup>	Qg		V <sub>DS</sub> = 20 V, I <sub>D</sub> = 20 A	-	61	92	nC	
Gate-source charge c	Q <sub>gs</sub>	$V_{GS} = 10 \text{ V}$		=	17	-		
Gate-drain charge <sup>c</sup>	Q <sub>gd</sub>			=.	17	-		
Gate resistance	$R_g$	f = 1 MHz		0.8	1.7	2.6	Ω	
Turn-on delay time <sup>c</sup>	t <sub>d(on)</sub>			-	17	27		
Rise time <sup>c</sup>	t <sub>r</sub>	$V_{DD} = 20 \text{ V}, \text{ R}_L = 1.0 \Omega,$ $I_D \cong 20 \text{ A}, \text{ V}_{GEN} = 10 \text{ V}, \text{ R}_g = 1 \Omega$		=.	19	29	ns	
Turn-off delay time <sup>c</sup>	t <sub>d(off)</sub>			=.	30	45		
Fall time <sup>c</sup>	t <sub>f</sub>			=	10	15		
Source-Drain Diode Ratings and Cha	aracteristics <sup>b</sup>							
Reverse recovery time	t <sub>rr</sub>	V <sub>DD</sub> = 32 V, I <sub>FM</sub> = 15 A, di/dt = 100 A/μs			40	80	ns	
Reverse recovery charge	Q <sub>rr</sub>			-	34	68	nC	
Reverse recovery current	I <sub>RM</sub>			-	-1.5	-	Α	
Pulsed current <sup>a</sup>	I <sub>SM</sub>			-	-	660	Α	
Forward voltage	V <sub>SD</sub>	$I_F = 50 \text{ A}, V_{GS} = 0$		_	0.8	1.1	V	

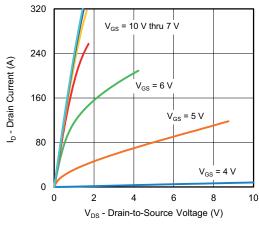
#### Notes

- a. Pulse test; pulse width  $\leq$  300  $\mu$ s, duty cycle  $\leq$  2 %
- b. Guaranteed by design, not subject to production testing
- c. Independent of operating temperature

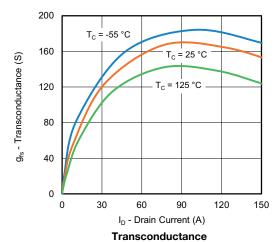
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

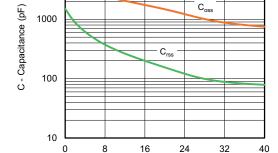


### **TYPICAL CHARACTERISTICS** (T<sub>A</sub> = 25 °C, unless otherwise noted)



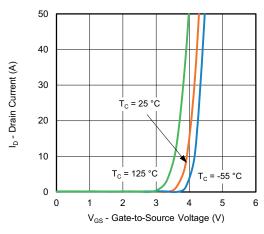
#### **Output Characteristics**



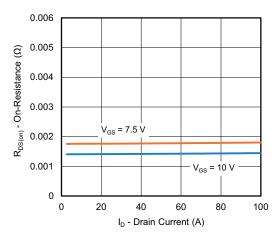


10 000

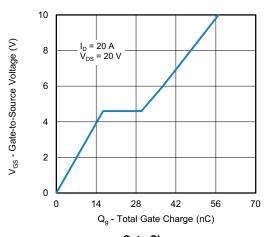
 $V_{DS}$  - Drain-to-Source Voltage (V) **Capacitance** 



**Transfer Characteristics** 



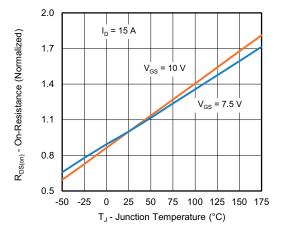
**On-Resistance vs. Drain Current** 



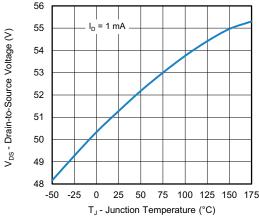
Gate Charge



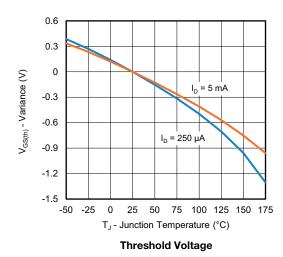
### **TYPICAL CHARACTERISTICS** (T<sub>A</sub> = 25 °C, unless otherwise noted)

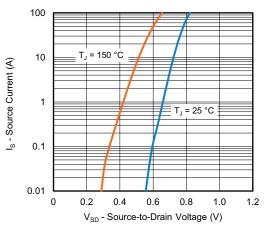


On-Resistance vs. Junction Temperature

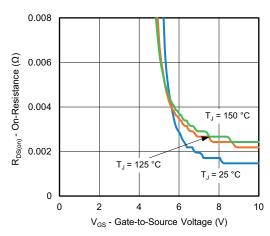


Drain Source Breakdown vs. Junction Temperature

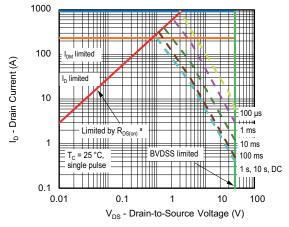




**Source Drain Diode Forward Voltage** 



On-Resistance vs. Gate-to-Source Voltage



Safe Operating Area

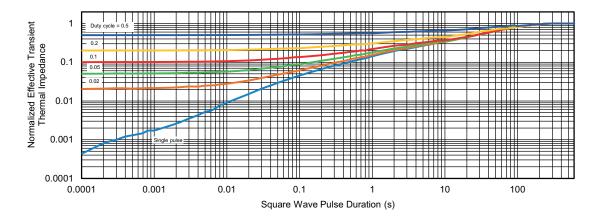
#### Note

a.  $V_{GS} > minimum V_{GS}$  at which  $R_{DS(on)}$  is specified

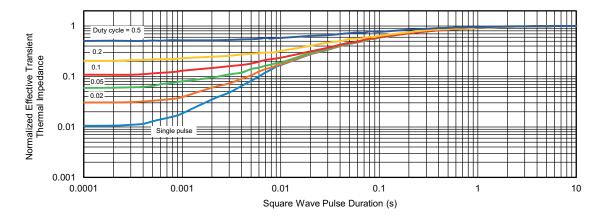
For technical questions, contact: automostechsuppor



### THERMAL RATINGS (T<sub>A</sub> = 25 °C, unless otherwise noted)



#### Normalized Thermal Transient Impedance, Junction-to-Ambient



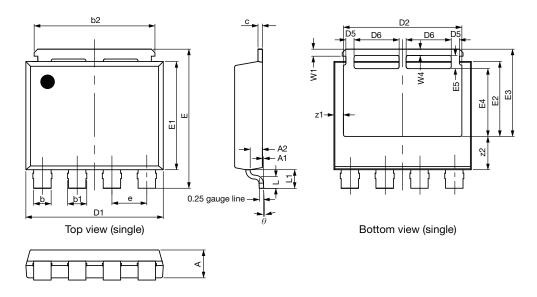
Normalized Thermal Transient Impedance, Junction-to-Case

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# PowerPAK® 8 x 8L BWL Case Outline 2



MIN. 1.50 0.00 0.655 0.92	1.60 - 0.705	MAX. 1.70 0.127	MIN. 0.059 0.000	<b>NOM.</b> 0.063	<b>MAX.</b> 0.067
0.00 0.655	-			0.063	0.067
0.655		0.127	0.000		
	0.705		0.000	-	0.005
0.92		0.755	0.026	0.028	0.030
	1.00	1.08	0.036	0.039	0.043
1.02	1.10	1.18	0.040	0.043	0.046
6.84	6.94	7.04	0.269	0.273	0.277
0.20	0.25	0.30	0.008	0.010	0.012
7.80	7.90	8.00	0.307	0.311	0.315
6.70	6.80	6.90	0.264	0.268	0.272
0.37	0.47	0.57	0.015	0.019	0.022
2.49	2.59	2.69	0.098	0.102	0.106
1.97	2.00	2.03	0.078	0.079	0.080
7.90	8.00	8.10	0.311	0.315	0.319
6.12	6.22	6.32	0.241	0.245	0.249
4.21	4.31	4.41	0.166	0.170	0.174
4.92	5.02	5.12	0.194	0.198	0.202
3.80	3.90	4.00	0.150	0.154	0.157
0.65	0.75	0.85	0.026	0.030	0.033
0.61	0.68	0.75	0.024	0.027	0.030
1.00	1.07	1.15	0.039	0.042	0.045
0.30	0.40	0.50	0.012	0.016	0.020
0.32	0.37	0.42	0.013	0.015	0.017
0.45	0.55	0.65	0.018	0.022	0.026
1.81	1.91	2.01	0.071	0.075	0.079
0°	-	5°	0°	-	5°
	1.02 6.84 0.20 7.80 6.70 0.37 2.49 1.97 7.90 6.12 4.21 4.92 3.80 0.65 0.61 1.00 0.30 0.32 0.45 1.81	1.02 1.10   6.84 6.94   0.20 0.25   7.80 7.90   6.70 6.80   0.37 0.47   2.49 2.59   1.97 2.00   7.90 8.00   6.12 6.22   4.21 4.31   4.92 5.02   3.80 3.90   0.65 0.75   0.61 0.68   1.00 1.07   0.30 0.40   0.32 0.37   0.45 0.55   1.81 1.91   0° -	1.02   1.10   1.18     6.84   6.94   7.04     0.20   0.25   0.30     7.80   7.90   8.00     6.70   6.80   6.90     0.37   0.47   0.57     2.49   2.59   2.69     1.97   2.00   2.03     7.90   8.00   8.10     6.12   6.22   6.32     4.21   4.31   4.41     4.92   5.02   5.12     3.80   3.90   4.00     0.65   0.75   0.85     0.61   0.68   0.75     1.00   1.07   1.15     0.30   0.40   0.50     0.32   0.37   0.42     0.45   0.55   0.65     1.81   1.91   2.01     0°   -   5°	1.02   1.10   1.18   0.040     6.84   6.94   7.04   0.269     0.20   0.25   0.30   0.008     7.80   7.90   8.00   0.307     6.70   6.80   6.90   0.264     0.37   0.47   0.57   0.015     2.49   2.59   2.69   0.098     1.97   2.00   2.03   0.078     7.90   8.00   8.10   0.311     6.12   6.22   6.32   0.241     4.21   4.31   4.41   0.166     4.92   5.02   5.12   0.194     3.80   3.90   4.00   0.150     0.65   0.75   0.85   0.026     0.61   0.68   0.75   0.024     1.00   1.07   1.15   0.039     0.32   0.37   0.42   0.013     0.45   0.55   0.65   0.018     1.81   1.91   2.01   0.071     0°   -   5°   0°	1.02     1.10     1.18     0.040     0.043       6.84     6.94     7.04     0.269     0.273       0.20     0.25     0.30     0.008     0.010       7.80     7.90     8.00     0.307     0.311       6.70     6.80     6.90     0.264     0.268       0.37     0.47     0.57     0.015     0.019       2.49     2.59     2.69     0.098     0.102       1.97     2.00     2.03     0.078     0.079       7.90     8.00     8.10     0.311     0.315       6.12     6.22     6.32     0.241     0.245       4.21     4.31     4.41     0.166     0.170       4.92     5.02     5.12     0.194     0.198       3.80     3.90     4.00     0.150     0.154       0.65     0.75     0.85     0.026     0.030       0.61     0.68     0.75     0.024     0.027       1.00     1.07     1.15

ECN: S19-0643-Rev. B, 05-Aug-2019

DWG: 6073

#### Note

Millimeter will govern

Revison: 05-Aug-2019 Document Number: 79736



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